74AHC595-Q100; 74AHCT595-Q100

8-bit serial-in/serial-out or parallel-out shift register with output latches

Rev. 2 — 26 May 2020

Product data sheet

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1. General description

The 74AHC595-Q100; 74AHCT595-Q100 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and 3-state outputs. Both the shift and storage register have separate clocks. The device features a serial input (DS) and a serial output (Q7S) to enable cascading and an asynchronous reset \overline{MR} input. A LOW on \overline{MR} will reset the shift register. Data is shifted on the LOW-to-HIGH transitions of the SHCP input. The data in the shift register is transferred to the storage register on a LOW-to-HIGH transition of the STCP input. If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register. Data in the storage register appears at the output whenever the output enable input (\overline{OE}) is LOW. A HIGH on \overline{OE} causes the outputs to assume a high-impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the registers. The 74AHCT595-Q100 features TTL compatible inputs. Both 74AHC595-Q100 and 74AHCT595-Q100 inputs are overvoltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)

 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 5.5 V
- Balanced propagation delays
- All inputs have Schmitt trigger action
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- CMOS low power dissipation
- Input levels:
 - The 74AHC595-Q100 operates with CMOS input levels
 - The 74AHCT595-Q100 operates with TTL input levels
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

3. Applications

- Serial-to-parallel data conversion
- Remote control holding register

4. Ordering information

| Type number | Package | | | | | | | | | |
|------------------|-------------------|----------|--|----------|--|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | | |
| 74AHC595D-Q100 | -40 °C to +125 °C | SO16 | plastic small outline package; 16 leads; | SOT109-1 | | | | | | |
| 74AHCT595D-Q100 | _ | | body width 3.9 mm | | | | | | | |
| 74AHC595PW-Q100 | -40 °C to +125 °C | TSSOP16 | plastic thin shrink small outline package; | SOT403-1 | | | | | | |
| 74AHCT595PW-Q100 | | | 16 leads; body width 4.4 mm | | | | | | | |
| 74AHC595BQ-Q100 | -40 °C to +125 °C | DHVQFN16 | plastic dual in-line compatible | SOT763-1 | | | | | | |
| 74AHCT595BQ-Q100 | | | thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm | | | | | | | |

5. Functional diagram

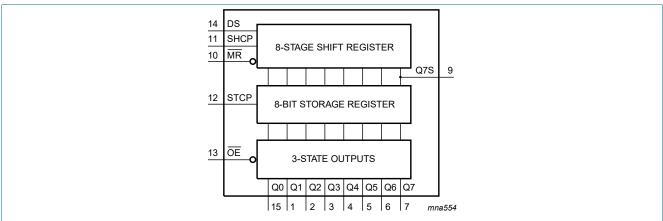
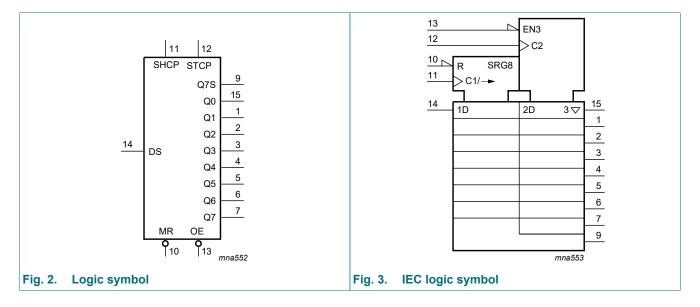
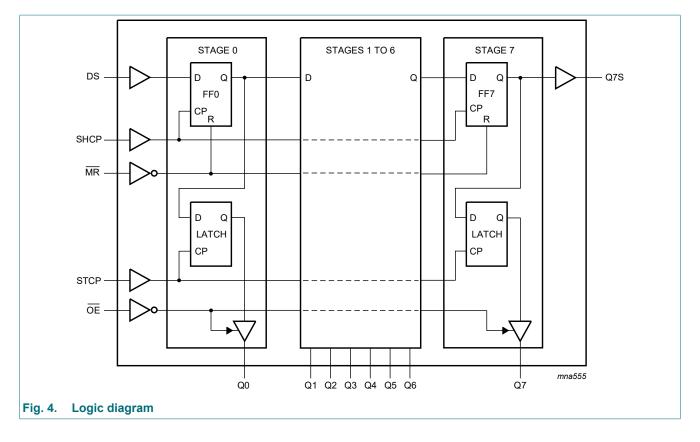
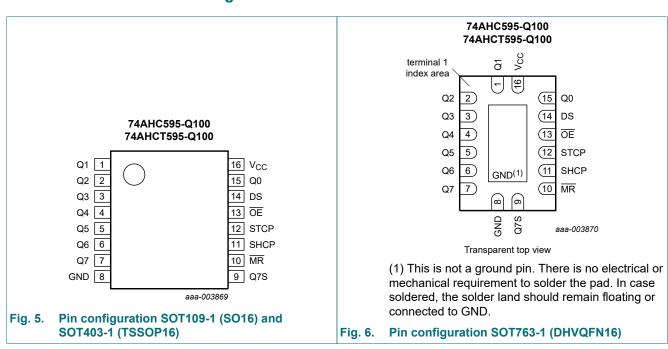


Fig. 1. Functional diagram





6. Pinning information



6.1. Pinning

6.2. Pin description

| Table 2. Pin description | | |
|--------------------------------|-------------------------|----------------------------------|
| Symbol | Pin | Description |
| Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7 | 15, 1, 2, 3, 4, 5, 6, 7 | parallel data output |
| GND | 8 | ground (0 V) |
| Q7S | 9 | serial data output |
| MR | 10 | master reset (active LOW) |
| SHCP | 11 | shift register clock input |
| STCP | 12 | storage register clock input |
| OE | 13 | output enable input (active LOW) |
| DS | 14 | serial data input |
| V _{CC} | 16 | supply voltage |

7. Functional description

Table 3. Function table

H = HIGH voltage state;

L = LOW voltage state;

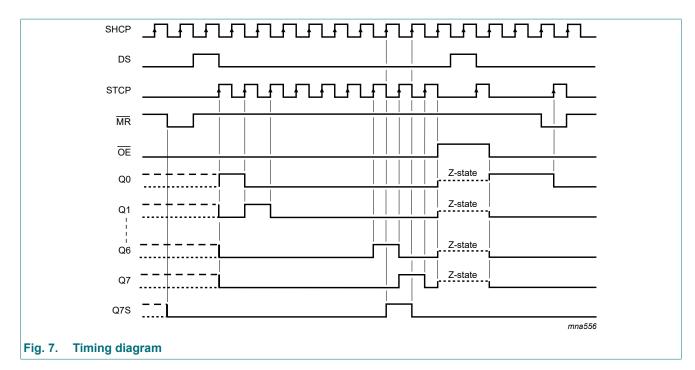
 \uparrow = LOW-to-HIGH transition;

X = don't care;

NC = no change;

Z = high-impedance OFF-state.

| Contro | I | | | Input | Output | t | Function |
|--------|----------|----|----|-------|--------|-----|--|
| SHCP | STCP | ŌE | MR | DS | Q7S | Qn | |
| Х | Х | L | L | Х | L | NC | a LOW-level on $\overline{\text{MR}}$ only affects the shift registers |
| Х | 1 | L | L | Х | L | L | empty shift register loaded into storage register |
| Х | Х | Н | L | Х | L | Z | shift register clear; parallel outputs in high-impedance OFF-state |
| 1 | X | L | Η | Н | Q6S | NC | logic HIGH-level shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S). |
| Х | ↑ | L | Н | Х | NC | QnS | contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages |
| 1 | 1 | L | Η | Х | Q6S | QnS | contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages |



8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|--|-----|------|------|------|
| V _{CC} | supply voltage | | | -0.5 | +7.0 | V |
| VI | input voltage | | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | V _I < -0.5 V | [1] | -20 | - | mA |
| Ι _{ΟΚ} | output clamping current | $V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V | [1] | -20 | +20 | mA |
| lo | output current | $V_{O} = -0.5 V$ to ($V_{CC} + 0.5 V$) | | -25 | +25 | mA |
| I _{CC} | supply current | | | - | +75 | mA |
| I _{GND} | ground current | | | -75 | - | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +125 °C | [2] | - | 500 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 5. Operating conditions

| Symbol | Parameter | Conditions | 74A | HC595-0 | Q100 | 74AH | Unit | | |
|------------------|-------------------------------------|----------------------------------|-----|---------|-----------------|------|------|-----------------|------|
| | | | Min | Тур | Max | Min | Тур | Max | |
| V _{CC} | supply voltage | | 2.0 | 5.0 | 5.5 | 4.5 | 5.0 | 5.5 | V |
| VI | input voltage | | 0 | - | 5.5 | 0 | - | 5.5 | V |
| Vo | output voltage | | 0 | - | V _{CC} | 0 | - | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 3.0 V to 3.6 V | - | - | 100 | - | - | - | ns/V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 20 | - | - | 20 | ns/V |

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | 25 °C | | | °C to 5 °C | | °C to 5 °C | Unit |
|-----------------|-----------------------------|---|------|-------|-------|------|---------------|------|---------------|------|
| | | | Min | Тур | Max | Min | Max | Min | Мах | 1 |
| 74AHC5 | 95-Q100 | | | | | | | | | |
| V _{IH} | HIGH-level | V _{CC} = 2.0 V | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| | input voltage | V _{CC} = 3.0 V | 2.1 | - | - | 2.1 | - | 2.1 | - | V |
| | | V _{CC} = 5.5 V | 3.85 | - | - | 3.85 | - | 3.85 | - | V |
| V _{IL} | LOW-level | V _{CC} = 2.0 V | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| | input voltage | V _{CC} = 3.0 V | - | - | 0.9 | - | 0.9 | - | 0.9 | V |
| | | V _{CC} = 5.5 V | - | - | 1.65 | - | 1.65 | - | 1.65 | V |
| V _{OH} | HIGH-level | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | | | |
| | output voltage | I _O = -50 μA; V _{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | 1.9 | - | V |
| | | I _O = -50 μA; V _{CC} = 3.0 V | 2.9 | 3.0 | - | 2.9 | - | 2.9 | - | V |
| | | I _O = -50 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.58 | - | - | 2.48 | - | 2.40 | - | V |
| | | I _O = -8.0 mA; V _{CC} = 4.5 V | 3.94 | - | - | 3.80 | - | 3.70 | - | V |
| V _{OL} | LOW-level | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | output voltage | I _O = 50 μA; V _{CC} = 2.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 50 μA; V _{CC} = 3.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 50 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| | | I _O = 8.0 mA; V _{CC} = 4.5 V | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| l _l | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | μA |
| I _{OZ} | OFF-state output current | $V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$ | - | - | ±0.25 | - | ±2.5 | - | ±10 | μA |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V | - | - | 4.0 | - | 40 | - | 80 | μA |
| CI | input capacitance | | - | 3 | 10 | - | 10 | - | 10 | pF |

74AHC_AHCT595_Q100

| Symbol | Parameter | Conditions | | 25 °C | | | °C to 5 °C | | °C to 5 °C | Unit |
|------------------|-----------------------------|--|------|-------|-------|------|---------------|------|---------------|------|
| | | | Min | Тур | Max | Min | Max | Min | Мах | 1 |
| 74AHCT | 595-Q100 | | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | - | - | 2.0 | - | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| V _{OH} | HIGH-level | $V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$ | | | | | | | | |
| | output voltage | l _O = -50 μA | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I _O = -8.0 mA | 3.94 | - | - | 3.80 | - | 3.70 | - | V |
| V _{OL} | LOW-level | $V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$ | | | | | | | | |
| | output voltage | l _O = 50 μA | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 8.0 mA | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| l _l | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | μA |
| I _{OZ} | OFF-state output current | $V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$ | - | - | ±0.25 | - | ±2.5 | - | ±10 | μA |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V | - | - | 4.0 | - | 40 | - | 80 | μA |
| ΔI _{CC} | additional supply current | per input pin; $V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $I_O = 0 A$; $V_{CC} = 4.5 V$ to 5.5 V | - | - | 1.35 | - | 1.5 | - | 1.5 | mA |
| CI | input capacitance | | - | 3 | 10 | - | 10 | - | 10 | pF |

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 13.

| Symbol | Parameter | Conditions | 25 °C | | | | °C to 5 °C | -40 ° +12 | Unit | |
|-----------------|-------------|---|-------|---------|------|-----|---------------|--------------|------|----|
| | | | Min | Typ [1] | Мах | Min | Мах | Min | Max |] |
| 74AHC5 | 95-Q100 | · · · · · · · · · · · · · · · · · · · | | | | | | | | |
| t _{pd} | propagation | SHCP to Q7S; see Fig. 8 [2] | | | | | | | | |
| | delay | V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF | - | 5.7 | 13.0 | 1.0 | 15.0 | 1.0 | 16.5 | ns |
| | | V_{CC} = 3.0 V to 3.6 V; C _L = 50 pF | - | 7.7 | 16.5 | 1.0 | 18.5 | 1.0 | 20.1 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 4.0 | 8.2 | 1.0 | 9.4 | 1.0 | 10.5 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C_L = 50 pF | - | 5.4 | 10.0 | 1.0 | 11.4 | 1.0 | 12.5 | ns |
| | | STCP to Qn; see Fig. 9 [2] | | | | | | | | |
| | | V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF | - | 5.9 | 11.9 | 1.0 | 13.5 | 1.0 | 15.0 | ns |
| | | V_{CC} = 3.0 V to 3.6 V; C _L = 50 pF | - | 7.7 | 15.4 | 1.0 | 17.0 | 1.0 | 18.5 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 4.2 | 7.4 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.5 | 9.0 | 1.0 | 10.5 | 1.0 | 11.5 | ns |

| Symbol | Parameter | Conditions | | 25 °C | | | °C to 5 °C | | °C to 5 °C | Unit |
|---------------------|----------------------------|--|-----|---------|------|-----|---------------|-----|---------------|------|
| | | | Min | Typ [1] | Мах | Min | Max | Min | Мах | 1 |
| t _{PHL} | HIGH | MR to Q7S; see Fig. 11 | | | | | | | | |
| | to LOW | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$ | | 5.9 | 12.8 | 1.0 | 13.7 | 1.0 | 15.0 | ns |
| | propagation delay | V_{CC} = 3.0 V to 3.6 V; C _L = 50 pF | - | 7.4 | 16.3 | 1.0 | 17.2 | 1.0 | 18.7 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 4.4 | 8.0 | 1.0 | 9.1 | 1.0 | 10.0 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.6 | 10.0 | 1.0 | 11.1 | 1.0 | 12.0 | ns |
| t _{en} | enable time | OE to Qn; see Fig. 12 [3] | | | | | | | | |
| | | V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF | - | 5.6 | 11.5 | 1.0 | 13.5 | 1.0 | 15.0 | ns |
| | | V_{CC} = 3.0 V to 3.6 V; C _L = 50 pF | - | 7.4 | 15.0 | 1.0 | 17.0 | 1.0 | 18.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 4.0 | 8.6 | 1.0 | 10.0 | 1.0 | 11.0 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.3 | 10.6 | 1.0 | 12.0 | 1.0 | 13.0 | ns |
| t _{dis} | disable time | OE to Qn; see <u>Fig. 12</u> [4] | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V; C _L = 15 pF | - | 5.4 | 11.0 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| | | V _{CC} = 3.0 V to 3.6 V; C _L = 50 pF | - | 8.7 | 15.7 | 1.0 | 16.2 | 1.0 | 17.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 3.8 | 8.0 | 1.0 | 9.5 | 1.0 | 10.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.8 | 10.3 | 1.0 | 11.0 | 1.0 | 12.0 | ns |
| f _{max} | maximum | SHCP or STCP; see Fig. 8 and Fig. 9 | | | | | | | | |
| | frequency | V _{CC} = 3.0 V to 3.6 V | 80 | 125 | - | 60 | - | 40 | - | MHz |
| | | V _{CC} = 4.5 V to 5.5 V | 130 | 170 | - | 110 | - | 90 | - | MHz |
| t _W | pulse width | SHCP HIGH or LOW; see Fig. 8 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 5.0 | _ | - | 5.0 | - | 5.0 | - | ns |
| | | STCP HIGH or LOW; see Fig. 9 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 5.0 | _ | - | 5.0 | - | 5.0 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | MR LOW; see Fig. 11 | | | | | | | | |
| | | $V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | $V_{CC} = 4.5 V \text{ to } 5.5 V$ | 5.0 | _ | - | 5.0 | _ | 5.0 | _ | ns |
| t _{su} | set-up time | DS to SHCP; see Fig. 10 | | | | | | | | |
| 30 | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 3.5 | - | - | 3.5 | _ | 3.5 | _ | ns |
| | | $V_{CC} = 4.5 V \text{ to } 5.5 V$ | 3.0 | - | - | 3.0 | _ | 3.0 | _ | ns |
| | | SHCP to STCP; see Fig. 9 | | | | | | | | |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 8.5 | - | _ | 8.5 | _ | 8.5 | _ | ns |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 5.0 | _ | - | 5.0 | _ | 5.0 | _ | ns |
| t _h | hold time | DS to SHCP; see Fig. 10 | | | | | | | | |
| 11 | | $V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 1.5 | - | - | 1.5 | _ | 1.5 | - | ns |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 2.0 | - | - | 2.0 | _ | 2.0 | _ | ns |
| t _{rec} | recovery | MR to SHCP; see Fig. 11 | | | | | | | | |
| 180 | time | $V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 3.0 | - | - | 3.0 | _ | 3.0 | _ | ns |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 2.5 | _ | _ | 2.5 | _ | 2.5 | _ | ns |
| C _{PD} | power | $f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{CC}$ [5] | - | 180 | - | - | | - | - | pF |
| U A C | dissipation capacitance | [6] | - | 100 | - | - | _ | _ | _ | ы |

| Symbol | Parameter | Conditions | | 25 °C | | - | °C to 5 °C | - | °C to 5 °C | Unit |
|------------------|-------------------------------------|--|-----|---------|------|-----|---------------|-----|---------------|------|
| | | | Min | Typ [1] | Мах | Min | Max | Min | Max | |
| 74AHCT | 595-Q100 | | | | | | 1 | | | |
| t _{pd} | propagation | SHCP to Q7S; see Fig. 8 [2] | | | | | | | | |
| | delay | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 3.8 | 8.2 | 1.0 | 9.0 | 1.0 | 10.0 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.2 | 10.0 | 1.0 | 11.0 | 1.0 | 12.0 | ns |
| | | STCP to Qn; see Fig. 9 [2] | | | | | | | | |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 4.0 | 7.4 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.3 | 9.0 | 1.0 | 10.5 | 1.0 | 11.5 | ns |
| t _{PHL} | HIGH | MR to Q7S; see Fig. 11 | | | | | | | | |
| | to LOW | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 4.6 | 8.2 | 1.0 | 9.5 | 1.0 | 10.5 | ns |
| | propagation delay | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.8 | 10.5 | 1.0 | 11.5 | 1.0 | 12.5 | ns |
| t _{en} | enable time | OE to Qn; see Fig. 12 [3] | | | | | | | | |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 4.8 | 9.0 | 1.0 | 11.0 | 1.0 | 12.0 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 6.2 | 11.6 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| t _{dis} | disable time | OE to Qn; see Fig. 12 [4] | | | | | | | | |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF | - | 3.6 | 6.9 | 1.0 | 8.0 | 1.0 | 9.0 | ns |
| | | V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF | - | 5.8 | 10.3 | 1.0 | 11.0 | 1.0 | 12.0 | ns |
| f _{max} | maximum frequency | SHCP and STCP; V _{CC} = 4.5 V to 5.5 V; see Fig. 8 and Fig. 9 | 130 | 170 | - | 110 | - | 90 | - | MHz |
| t _W | pulse width | SHCP HIGH or LOW; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 8</u> | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | STCP HIGH or LOW; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 9</u> | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | MR LOW; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 11</u> | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| t _{su} | set-up time | DS to SHCP; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 10</u> | 3.0 | - | - | 3.0 | - | 3.0 | - | ns |
| | | SHCP to STCP; V_{CC} = 4.5 V to 5.5 V; see Fig. 9 | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| t _h | hold time | DS to SHCP; V_{CC} = 4.5 V to 5.5 V; see Fig. 10 | 2.0 | - | - | 2.0 | - | 2.0 | - | ns |
| t _{rec} | recovery time | MR to SHCP; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 11</u> | 3.0 | - | - | 3.0 | - | 3.0 | - | ns |
| C _{PD} | power dissipation capacitance | $f_i = 1 \text{ MHz}; V_1 = \text{GND to } V_{CC}$ [5] [6] | | 190 | - | - | - | - | - | pF |

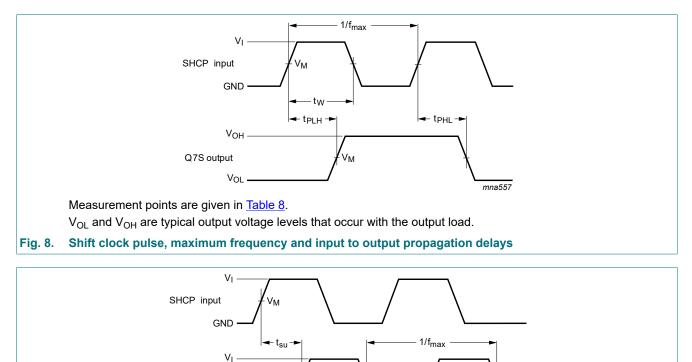
[1] Typical values are measured at nominal supply voltage.

 t_{pd} is the same as t_{PHL} and t_{PLH} . [2] [3]

 t_{en} is the same as t_{PZL} and t_{PZH} .

[4] t_{dis} is the same as t_{PLZ} and t_{PHZ} . [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; f_o = output frequency in MHz; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs; C_L = output load capacitance in pF; V_{CC} = supply voltage in V.

[6] All 9 outputs switching.



11.1. Waveforms and test circuit

 $V_{OH} \xrightarrow{V_{OH}} V_{M}$ $V_{OL} \xrightarrow{V_{OL}} V_{M}$ Measurement points are given in <u>Table 8</u>. V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

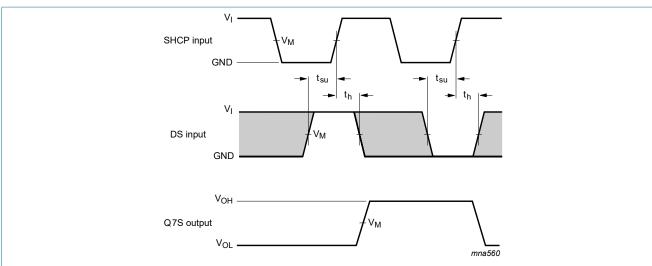
VM

tω

Fig. 9. Storage clock to output propagation delays

STCP input

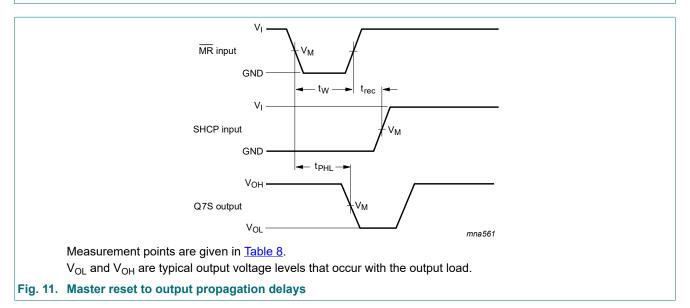
GND



Measurement points are given in Table 8.

The shaded areas indicate when the input is permitted to change for predictable output performance. V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 10. Data set-up and hold times



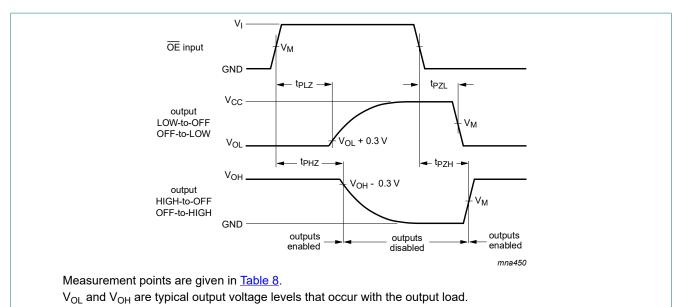


Fig. 12. Enable and disable times

Table 8. Measurement points

| Туре | Input | Output |
|----------------|--------------------|--------------------|
| | V _M | V _M |
| 74AHC595-Q100 | 0.5V _{CC} | 0.5V _{CC} |
| 74AHCT595-Q100 | 1.5 V | 0.5V _{CC} |

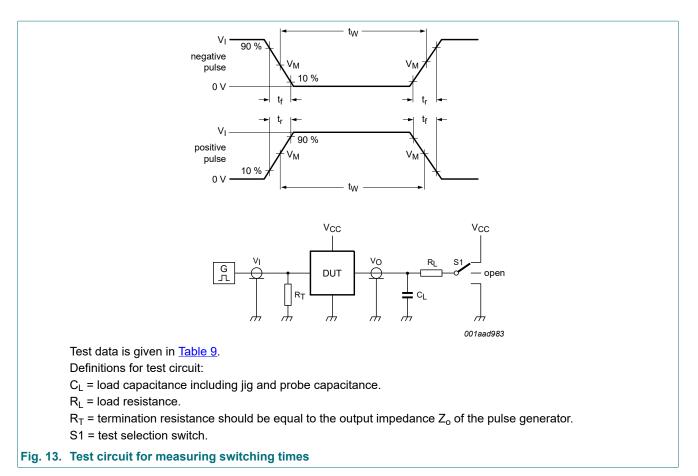


Table 9. Test data

| Туре | Input | | Load | | S1 position | | | |
|----------------|-----------------|---------------------------------|--|------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| | VI | t _r , t _f | C _L R _L t _P | | t _{PHL} , t _{PLH} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| 74AHC595-Q100 | V _{CC} | ≤ 3.0 ns | 15 pF, 50 pF | 1 kΩ | open | GND | V _{CC} | |
| 74AHCT595-Q100 | 3.0 V | ≤ 3.0 ns | 15 pF, 50 pF | 1 kΩ | open | GND | V _{CC} | |

12. Package outline

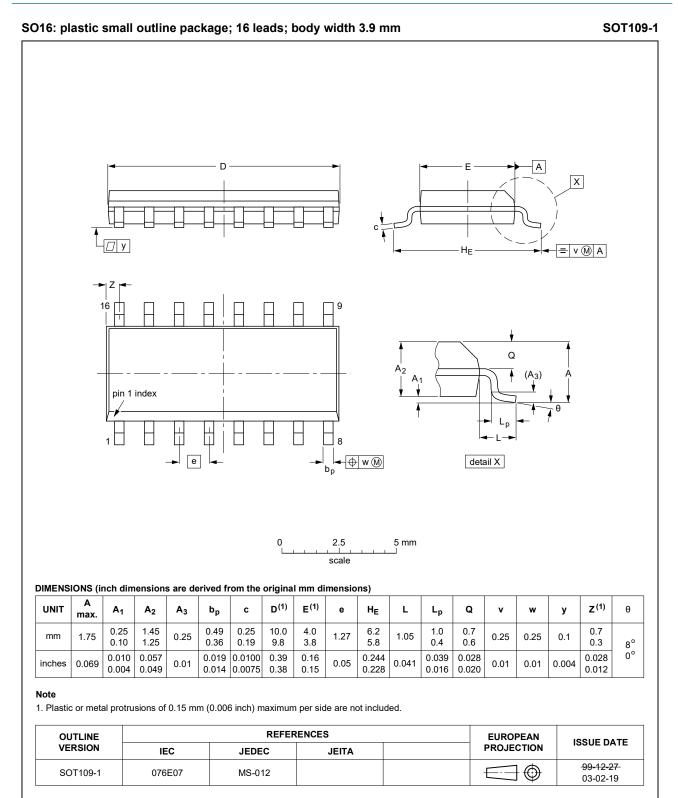


Fig. 14. Package outline SOT109-1 (SO16)

74AHC_AHCT595_Q100

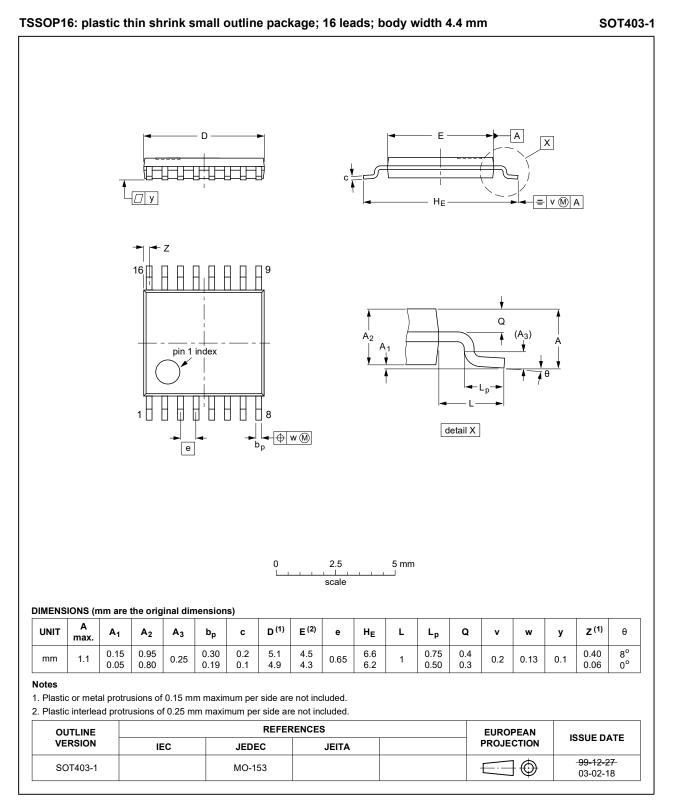


Fig. 15. Package outline SOT403-1 (TSSOP16)

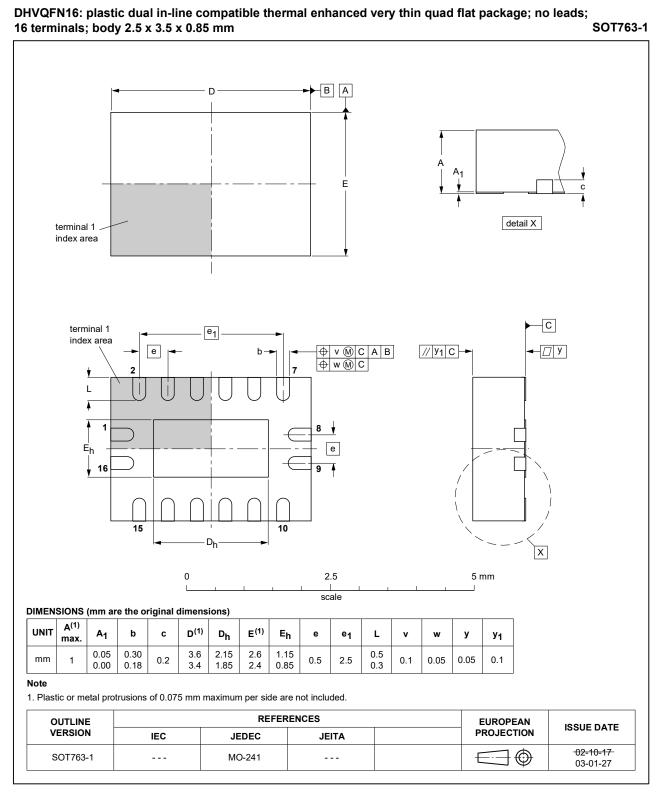


Fig. 16. Package outline SOT763-1 (DHVQFN16)

13. Abbreviations

| Table 10. Abbreviations | | | |
|-------------------------|---|--|--|
| Acronym | Description | | |
| CMOS | Complementary Metal-Oxide Semiconductor | | |
| ESD | ElectroStatic Discharge | | |
| HBM | Human Body Model | | |
| MIL | Military | | |
| MM | Machine Model | | |
| TTL | Transistor-Transistor Logic | | |

14. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|------------------------|---|---|--|------------------------|
| 74AHC_AHCT595_Q100 v.2 | 20200526 | Product data sheet | - | 74AHC_AHCT595_Q100 v.1 |
| Modifications: | guidelines o Legal texts l <u>Section 1</u> ar <u>Fig. 7</u> : Timin <u>Table 4</u> : Der | of this data sheet has been f Nexperia. nave been adapted to the r nd <u>Section 2</u> updated. ng diagram updated with SI rating values for P _{tot} total p pagation delay symbol and | new company nan HCP waveform. ower dissipation u | ne where appropriate. |
| 74AHC_AHCT595_Q100 v.1 | 20120712 | Product data sheet | - | - |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition | | |
|-----------------------------------|-----------------------|---|--|--|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. | | |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. | | |
| Product [short] data sheet | Production | This document contains the product specification. | | |

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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